

HRW34

Silicon Schottky Barrier Diode for High Frequency Rectifying

HITACHI

Rev. 2
Nov. 1994

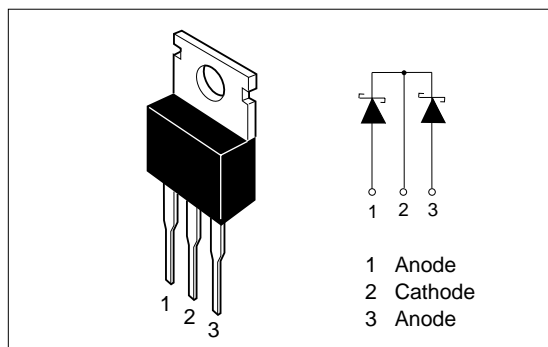
Features

- Low forward voltage drop. ($V_F = 0.80V$ max)
- High reverse voltage. ($V_R = 90V$ max)

Ordering Information

Type No.	Laser Mark	Package Code
HRW34	HRW34	TO-220AB

Pin Arrangement



Absolute Maximum Ratings ($T_a = 25^\circ C$) *

Item	Symbol	Value	Unit
Repetitive peak reverse voltage	V_{RRM}	90	V
Average forward current	I_o^{**}	5	A
Non-Repetitive peak forward surge current	I_{FSM}^{***}	60	A
Junction temperature	T_j	125	$^\circ C$
Storage temperature	T_{stg}	-40 to +125	$^\circ C$

* Per one device

** Square wave, Duty (1/2), $T_c = 95^\circ C$, Sum of two devices

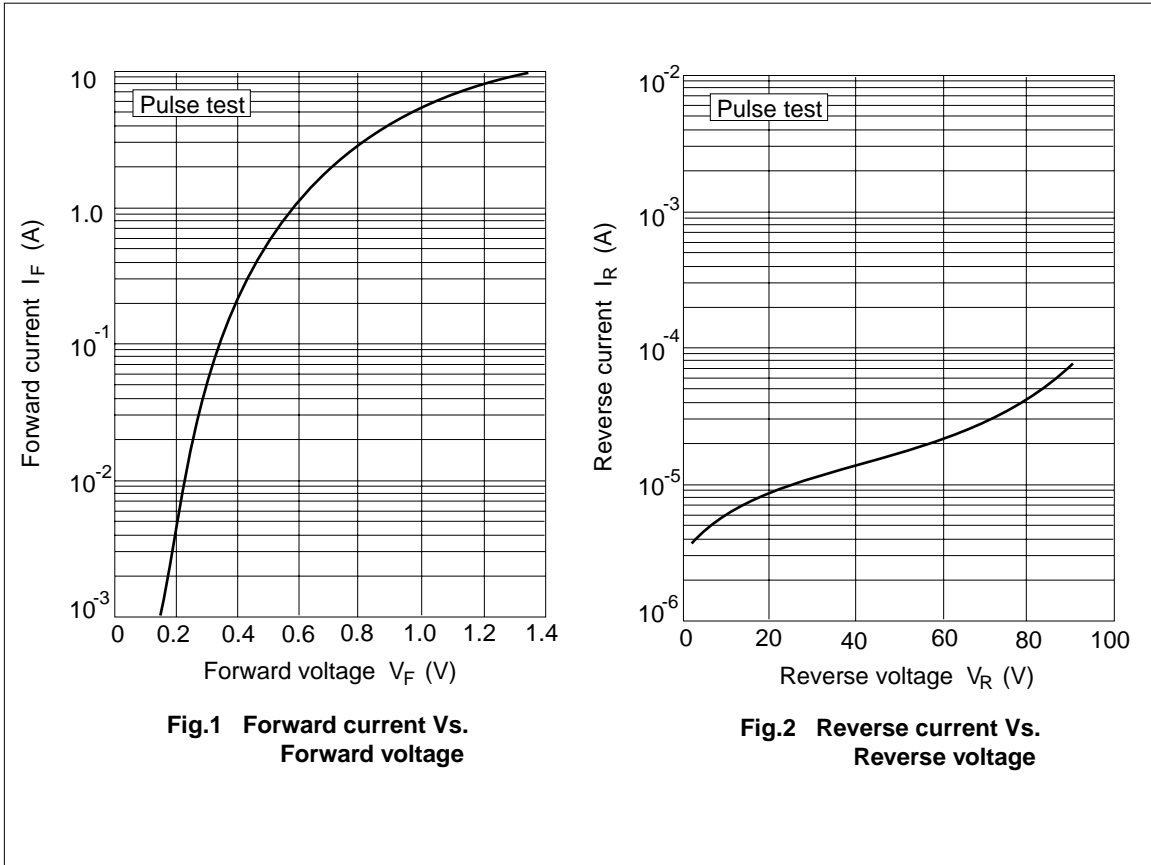
*** Half sine wave 10msec

Electrical Characteristics ($T_a = 25^\circ C$) *

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Forward voltage	V_{F1}	—	0.55	0.60	V	$I_F = 1.0 A$
	V_{F2}	—	0.75	0.80		$I_F = 2.0 A$
Reverse current	I_R	—	—	2.0	mA	$V_R = 90 V$

* Per one device

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Package Dimensions

Unit: mm

